

Moire pattern of 2D materials

Overview:

Students explore the alignment of lattices of layers of graphite graphically to reveal emergent patterns.

Essential Question:

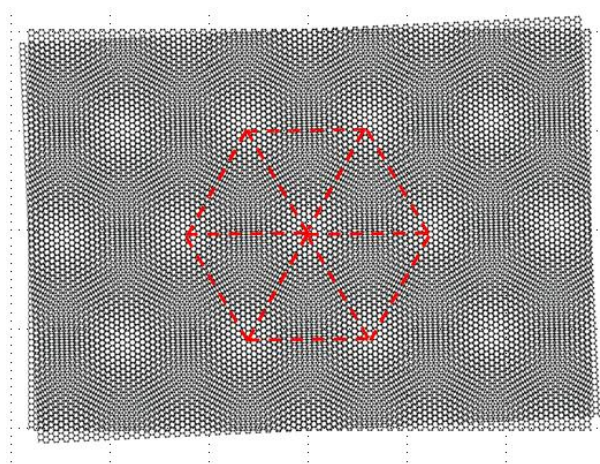
How does a superlattice form when stacking two layer of 2D materials?

Background:

Basic concepts:

Crystal lattice, crystal axis, unit cell, lattice constant, superlattice, electron,

After the discovery of graphene in 2004, a huge family of two dimensional materials have been identified and realized in recent decade, covering a wide category of materials from normal metal, semiconductor, insulator, to materials with more exotic phases, like magnet and superconductor. It is then a current ongoing effort in the field to build heterostructures with different 2D materials as building blocks, to realize material system with even more exotic properties or to match application goals.



When stack two layer of 2D materials together, it is important to control the alignment of the crystalline axis of the two layers. A small misalignment in the crystalline axis results in a superlattice on a much larger scale compared with the original lattice unit cell. This superlattice is known as Moire superlattice and has a fundamental role in heterostructures with a small twist angle. Recently, it has been shown that when stack two monolayer graphene together with an twist angle close to 1.1 degree, the Moire superlattice give rise to unique flat electronic bands near fermi surface and results in numerous strongly correlated phases, such as Correlated insulator, superconductivity, ferromagnetism and topological Chern insulator.

This demo aims to introduce the concept of Moire superlattice, and visualize its formation and relation with twist angle. This demo only uses graphene and h-BN as example.

Research Connection:

This demo is very closely related with the cutting edge research ongoing in Prof. Xiaodong Xu's Lab and Prof. Matthew Yankowitz's Lab.

NGSS Standards:

Standard Number	Standard text
HS-PS2-6.	Communicate scientific and technical information about why the molecular-level structure is important in the functioning of designed materials.
SEP2	Developing and using Models
CC 1	Patterns

Materials:

- Graphene lattice structure printed on the transparent films or PowerPoint model.
- hBN lattice printed on the transparent films with same structure, lattice constant 5% larger than graphene lattice. In reality, the hBN lattice constant is only 1.8% larger than graphene, here we take it for 5% in order to see difference clearly.

Procedure:

1. How does a superlattice form when stacking two layer of 2D materials?
Play with demo (printed sheets or PowerPoint file) and you can easily find out.
2. What is the relation between the period of the superlattice (Moire period, d) and twist angle (θ)?
 - a. For every 60 degree twist angle rotation, the superlattice become the same (six fold rotational symmetry)
 - b. Within 0 to 60 degree, the larger twist angle is, the smaller Moire period is.
 - c. For quantitative relation between d and θ , in graphene-graphene Moire pattern

$$d = \frac{a}{2 \sin \frac{\theta}{2}}$$

where a is the lattice constant of graphene ($a=0.246\text{nm}$ in reality)

3. What is the difference between graphene-graphene Moire pattern and graphene-hBN Moire pattern?
For graphene-graphene Moire pattern, there is no superlattice form with twist angle of 0. But for graphene-hBN, even at twist angle 0, there is a superlattice.
4. How to understand that Moire pattern would change the electronic and optical properties of the materials systems? (from a very naïve way)
Upon forming the Moire pattern, the lattice structure can be categorized as AA sites and AB/BA sites on a large scale. When electron move inside this crystal, it feels different potential on AA sites and AB/BA sites, therefore it will have preference to reside not uniformly in the lattice but on AA site only.

References:

Seyler, K.L., Rivera, P., Yu, H. et al. Signatures of moiré-trapped valley excitons in MoSe₂/WSe₂ heterobilayers. Nature 567, 66–70 (2019). <https://doi.org/10.1038/s41586-019-0957-1>

He, M. et al. Tunable correlation-driven symmetry breaking in twisted double bilayer graphene.
arXiv:2002.08904.

Chen, S. He, M et al. Electrically tunable correlated and topological states in twisted monolayer-bilayer graphene. <https://arxiv.org/abs/2004.11340>

Resources:

Moire pattern of 2D materials.pptx

Sources:

- Laser printer transparencies

https://www.amazon.com/gp/product/B07KP1G6DV/ref=ppx_yo_dt_b_asin_title_o00_s00?ie=UTF8&psc=1